

Supporting Information

Methylated naphthalene additives with various melting and boiling points enable a win-win scenario of optimizing both cost and efficiency of polymer solar cells

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1. Analytical Instruments

Ultraviolet-visible (UV-vis) absorption spectra were measured on Agilent Cary60 spectrometer. The photoluminescence (PL) spectrum was conducted on an HORIBA Instrument QM40. Thermal gravimetric analysis (TGA) was performed under nitrogen at a heating rate of 5 °C min⁻¹ with TGA Q50 analyzer. The morphologies of the four blend films were characterized by atomic force microscopy (AFM, Multimode 8 with a tapping mode). Grazing incidence wide angle X-ray scattering (GIWAXS) was performed at 1W1A Diffuse X-ray Scattering Station, Beijing Synchrotron Radiation Facility (BSRF-1W1A), China. The samples were prepared in silicon substrates using identical blend solutions and conditions as those used in device fabrication. The solution of each pure organic material was spin-coated on cleaned ITO substrates. Droplets of two

different liquids, water and ethylene glycol (EG) were cast onto the pure organic films with the drop size kept at 1 μL per drop. Contact angle images were taken at 4 s after the whole droplet was deposited onto the sample surface. At least 3 independent measurements were performed for each single liquid.

2. Measurement of hole and electron mobilities

The charge carrier mobilities of the binary active layers were measured by using the space-charge-limited current (SCLC) method. Hole-only devices with a structure of ITO/PEDOT:PSS/active layer/MoO₃/Ag and electron-only devices with a structure of ITO/ZnO/active layer/PFN-Br/Ag were fabricated. The device characteristics were extracted by modeling the dark current under forward bias using the SCLC expression described by the Mott-Gurney law:

$$J = \frac{9}{8} \varepsilon_r \varepsilon_0 \mu \frac{V^2}{L^3}$$

Here, $\varepsilon_r \approx 3$ is the average dielectric constant of blend film, ε_0 is the permittivity of the free space, μ is the carrier mobility, L is the thickness of active layers, and V is the applied voltage.

3. Charge transport, exciton dissociation, and charge collection properties

V_{OC} and P_{light} follow the relationship: $V_{\text{OC}} \propto nK_{\text{B}}T/q \ln(P_{\text{light}})$, the value of n determines the main charge recombination type of PSCs. J_{SC} and P_{light} satisfy the equation: $J_{\text{SC}} \propto P_{\text{light}}^{\alpha}$, the value of α reflects the strength of bimolecular recombination. J_{ph} satisfies the equation: $J_{\text{ph}} = J_{\text{L}} - J_{\text{D}}$, V_{eff} can be defined as $V_{\text{eff}} = V_0 - V_{\text{appl}}$ (J_{L} and J_{D} stand for the current density in bright and dark environments, V_0 represents the voltage when the J_{ph} is equal to zero, and the V_{appl} refers to the voltage applied to the device). The exciton dissociation probability ($P(E, T)$) can be acquired from the $J_{\text{ph}} - V_{\text{eff}}$ curves, and the value of $J_{\text{ph}}/J_{\text{sat}}$ determines the $P(E, T)$. The charge collection efficiency (P_{Coll}) value is determined by the value $J_{\text{max}}/J_{\text{sat}}$ (J_{max} is the current density when the device is under the condition of the maximum output power).

4. Supplementary Figures

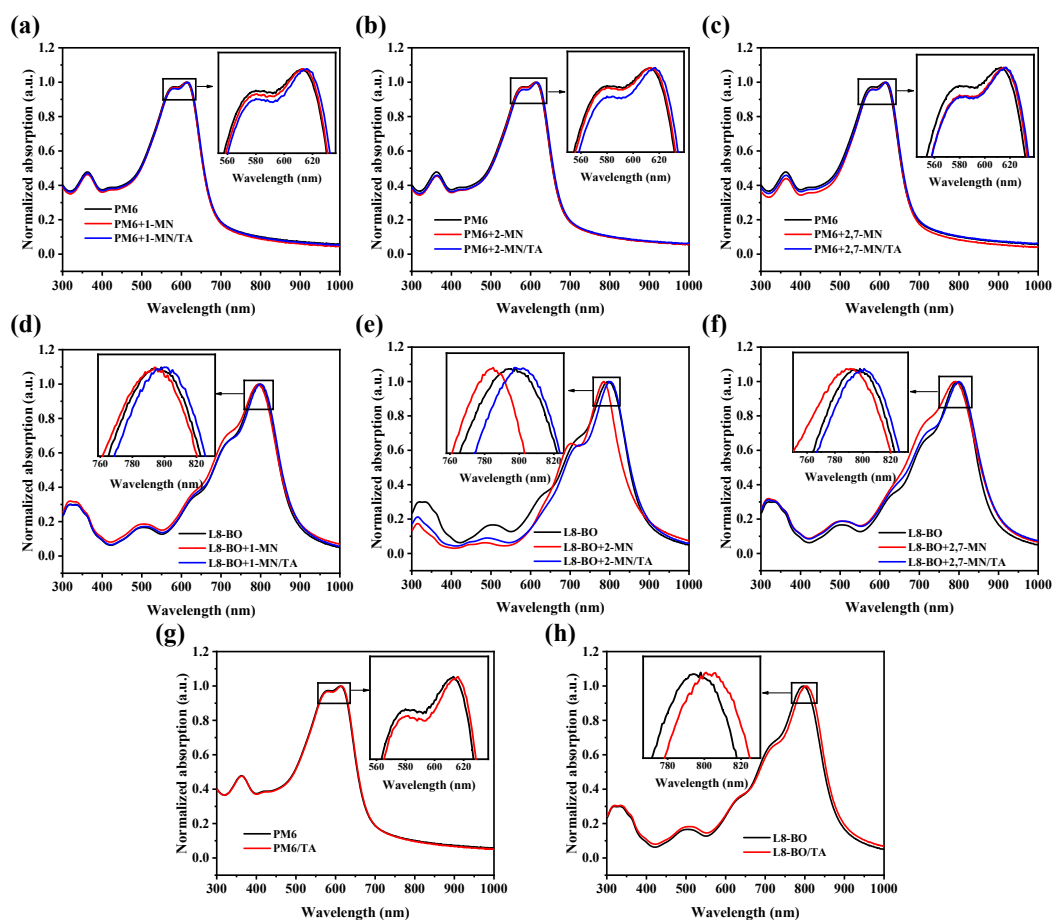


Fig. S1. UV-vis absorption spectra of PM6 film and L8-BO film under different conditions.

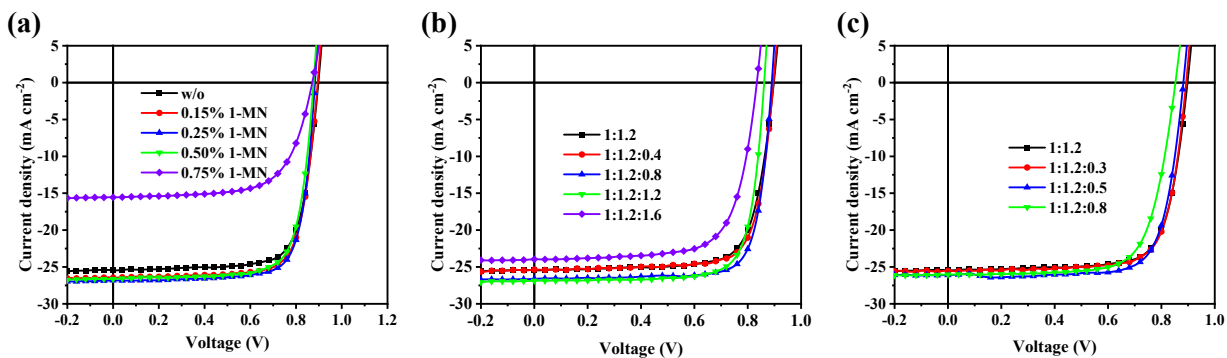


Fig. S2. The J - V curves of the device processed with different additive ratio: (a) 1-MN ratios, (b) 2-MN ratios, and (c) 2,7-MN ratios.

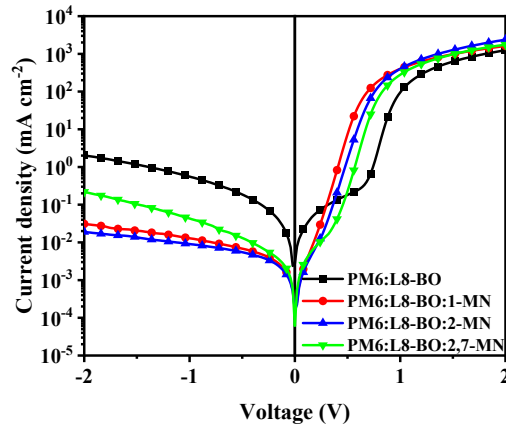


Fig. S3. The dark current curves of the device under different conditions.

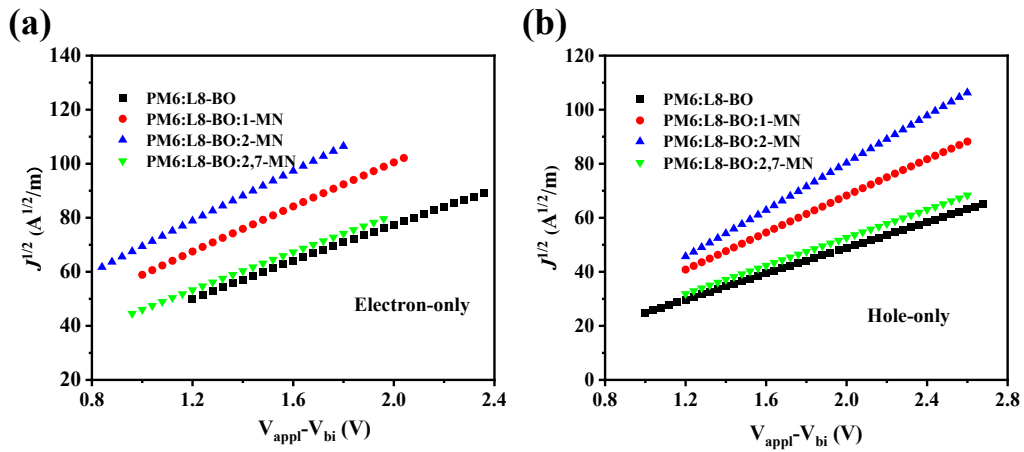


Fig. S4. (a) μ_e and (b) μ_h of the device processed without/with different additives.

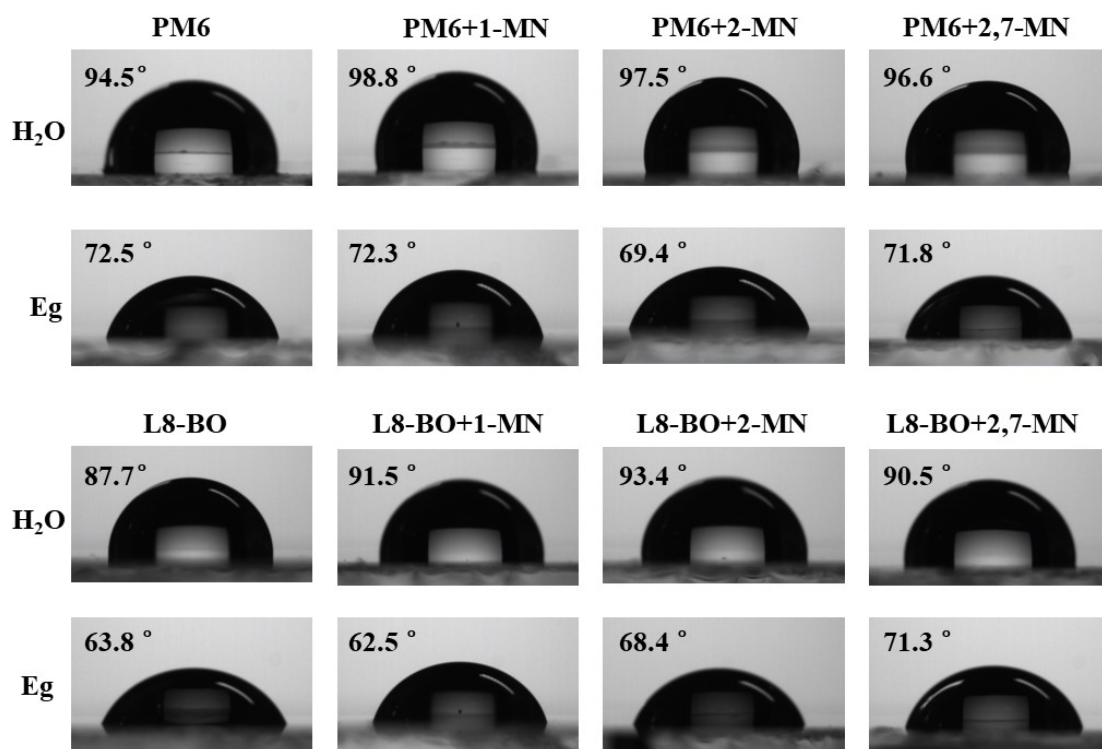


Fig. S5. Contact angles of PM6 and L8-BO films under different conditions.

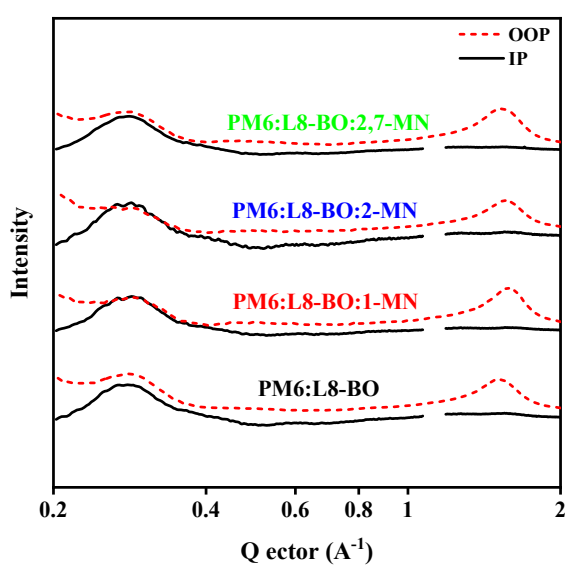


Fig. S6. The OOP and IP line cuts from 2D GIWAXS patterns.

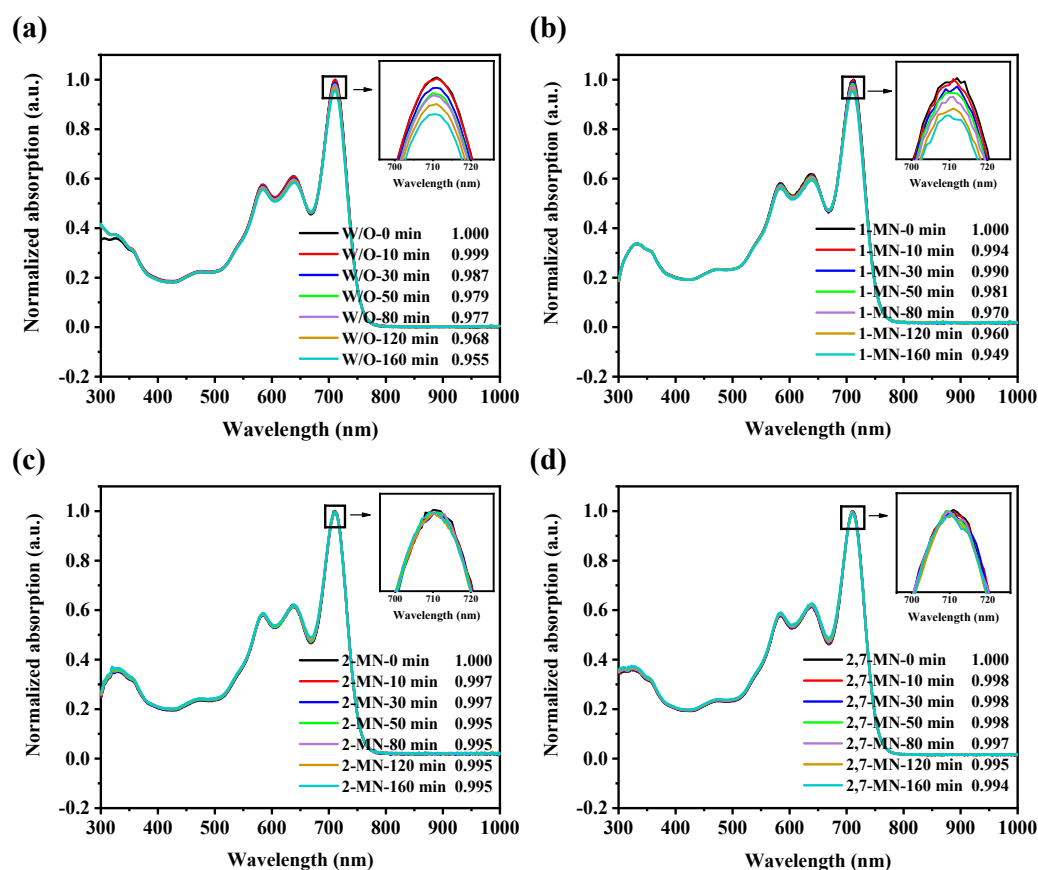


Fig. S7. UV-vis absorption spectra of the PM6/L8-BO blend solution under different conditions.

5. Supplemental Tables

Table S1. The prices of some reported non-halogenated volatile solid additives and corresponding FF and PCE of PSCs.

Additives	Price (from Energy Chemical)	FF [%]	PCE [%]	System	Ref.
NA	¥ 20/100g	78.42	16.52	PM6:Y6	[1]
2-MON	¥ 25/25g	76.40	17.32	PM6:PY-DT	[2]
DMON	¥ 774/25g	59.30	11.19	PBDB-T:TTC8- O1-4F	[3]

BDT	¥4760/5g	77.11	17.91	PM6:Y6	[4]
Ph	¥451/25g	77.82	18.47	D18-Cl:N3	[5]
DBT	¥62/25g	79.33	18.87	PM6:L8-BO	[6]
9-FL	¥25/25g	79.00	18.60	PM6:BTP-eC9	[7]
TT	¥720/25g	75.10	17.75	PM6:Y6	[8]
DTT-3	¥2159/5g	73.60	14.82	PM6:L15	[9]
DOB	¥22/25g	75.60	17.05	PM6:L8-BO	[10]
TMB	¥31/25g	79.95	18.61	PBDB-TF:eC9	[11]
BPO	¥20/25g	70.70	8.03	PTB7:PC ₇₁ BM	[12]
Bipy	¥44/25g	69.44	8.73	J51:N2200	[13]
2T	¥66/25g	78.60	18.10	PM6:Y6	[14]
Fc	¥45/100g	76.00	17.40	PM6:Y6	[15]
TPA	¥39/25g	77.65	17.30	PM6:BTP-eC9	[16]
2-MN	¥30/25g	78.91	18.70	PM6:L8-BO	This work

Table S2. Photovoltaic performance of the device with different **1-MN** ratios.

additive	V_{OC} [V]	J_{SC} [mA cm ⁻²]	FF [%]	PCE [%]
w/o	0.898	25.45	75.08	17.15
0.15% 1-MN	0.895	26.43	75.83	17.94
0.25% 1-MN	0.883	26.82	77.22	18.29
0.50% 1-MN	0.877	26.63	75.41	17.61
0.75% 1-MN	0.871	15.55	66.91	9.06

Table S3. Photovoltaic performance of the device with different **2-MN** ratios.

PM6:L8-BO:2-MN	V_{oc} [V]	J_{sc} [mA cm ⁻²]	FF [%]	PCE [%]
w/o	0.898	25.45	75.08	17.15
1:1.2:0.4	0.896	25.36	76.97	17.50
1:1.2:0.8	0.890	26.61	78.91	18.70
1:1.2:1.2	0.862	26.87	77.76	18.01
1:1.2:1.6	0.834	23.95	71.08	14.20

Table S4. Photovoltaic performance of the device with different 2,7-MN ratios.

PM6:L8-BO:2,7-MN	V_{oc} [V]	J_{sc} [mA cm ⁻²]	FF [%]	PCE [%]
w/o	0.898	25.45	75.08	17.15
1:1.2:0.3	0.893	25.53	75.62	17.24
1:1.2:0.5	0.882	26.09	76.20	17.55
1:1.2:0.8	0.853	26.03	72.50	16.09

Table S5. The FF and PCE of some previously reported binary PSCs treated with non-halogenated solid additives.

Additives	FF[%]	PCE [%]	System	Ref.
DOB	75.60	17.05	PM6:L8-BO	[10]
DSB	73.90	15.59	PM6:L8-BO	[10]
IDT(BDT-IC) ₂	71.24	16.34	PM6:Y6	[17]
2T	78.60	18.10	PM6:Y6	[14]
4T	76.80	17.20	PM6:Y6	[14]
9-FL	79.00	18.60	PM6:BTP-eC9	[7]
TOHA	76.20	17.91	D18-Cl:N3	[18]
BDT	77.11	17.91	PM6:Y6	[4]
ROPD	66.45	8.33	PTB7-Th:PC ₇₁ BM	[19]
DDO	70.09	10.10	BTR:PC ₇₁ BM	[20]
2-HM	79.40	18.85	PM6:L8-BO	[21]
2-MN(2-methoxynaphthalene)	76.40	17.32	PM6:PY-DT	[2]
TTA	73.46	15.80	PM6:BTP-eC9	[16]
TPA	77.65	17.30	PM6:BTP-eC9	[16]
DTB	70.50	14.50	PBDB-T:BO4Cl	[22]
Ph	77.82	18.47	D18-Cl:N3	[5]
DBT	79.33	18.87	PM6:L8-BO	[6]
NA	78.42	16.52	PM6:Y6	[1]

NDT	78.10	18.85	PM6:L8-BO	[23]
ADT	68.10	14.75	PM6:Y6	[23]
BTO	79.00	19.05	PM6:L8-BO	[24]
TT	75.10	17.75	PM6:Y6	[8]
SA-1	75.00	13.70	PBDB-TCI:IT-4F	[25]
SA-2	75.00	13.30	PBDB-TF:IT-4F	[25]
SA-3	75.00	13.20	PBDB-TF:IT-4F	[25]
SA-4	74.80	13.50	PBDB-TCI:IT-4F	[26]
SA-7	70.50	12.10	PBDB-TCI:IT-4F	[26]
SA-8	56.00	9.30	PBDB-TF:IT-4F	[25]
DTT-1	73.71	16.72	PM6:L15	[9]
DTT-2	77.26	18.72	PM6:L15	[9]
DTT-3	73.60	14.82	PM6:L15	[9]
Au:NCNT	71.78	9.45	PTB7:PC ₇₀ BM	[27]
Au:BCNT	72.09	9.81	PTB7:PC ₇₀ BM	[27]
GO-TPP	62.1	8.58	PTB7:PC ₇₁ BM	[28]
GO-TPP	58.4	6.92	PCDTBT:PC ₇₁ BM	[28]
N-GCD	71	8.6	PTB7:PC ₇₁ BM	[29]
BPQD	67.2	8.71	PTB7:PC ₇₁ BM	[30]
BPO	70.7	8.03	PTB7:PC ₇₁ BM	[12]
2,3-DHP	67	4.44	P3HT:PC ₆₁ BM	[31]
2,3-DHP	66	5.06	P3HT:IC ₆₀ BA	[32]
2-DHP	64	4.22	P3HT:PC ₆₁ BM	[33]
2,4-DHP	61	3.47	P3HT:PC ₆₁ BM	[33]
FCA	72.65	12.31	PBDB-T:IT-M	[34]
BP-BP	70.28	12.41	PBDB-T:ITIC	[35]
Fc	76	17.40	PM6:Y6	[15]
Bipy	69.44	8.73	J51:N2200	[13]
PID	74	15.9	PM6:Y6	[36]
M1	79.5	17.57	DAPor:6TIC	[37]
M2	77.1	16.70	DAPor:6TIC	[37]
2-MN	78.91	18.70	PM6:L8-BO	This work

Table S6. Relevant parameters obtained from the J_{ph} - V_{eff} Curve.

Additives	J_{sat} [mA cm ⁻²]	J_{ph} [mA cm ⁻²]	J_{max} [mA cm ⁻²]	J_{ph}/J_{sat}	J_{max}/J_{sat}
w/o	27.07	25.88	23.13	95.60%	85.45%
1-MN	27.04	26.26	24.19	97.12%	89.46%
2-MN	27.46	27.07	24.60	98.58%	89.58%
2,7-MN	27.16	26.20	24.04	96.47%	88.51%

Table S7. Contact angle, surface energy, and compatibility parameters for PM6 and L8-BO films under different conditions.

Films	Contact angle (deg)		γ mN m ⁻¹	$\chi_{\text{donor-acceptor}}$
	H ₂ O	Eg		
PM6	94.5	72.5	21.91	0.20
L8-BO	87.7	63.8	26.29	
PM6+1-MN	98.8	72.3	25.69	0.22
L8-BO+1-MN	91.5	62.5	30.69	
PM6+2-MN	97.5	69.4	28.18	0.07
L8-BO+2-MN	93.4	68.4	25.39	
PM6+2,7-MN	96.6	71.8	24.17	0.09
L8-BO+2,7-MN	90.5	71.3	21.31	

Table S8. The positions, *d*-spacing, FWHM, and CCL of the (010) and (100) peaks of the BHJ film with different additive treatments.

Blend films	Out-Of-plane π - π stacking cell long axis (010)				In-plane Unit cell long axis (100)			
	q	d- spacin g	FWHM	CCL	q	d- spacing	FWHM	CCL
	[Å ⁻¹]	[Å]	[Å ⁻¹]	[Å]	[Å ⁻¹]	[Å]	[Å ⁻¹]	[Å]
PM6:L8-BO	1.500	4.188	0.307	20.47	0.283	22.175	0.075	84.34
PM6:L8-BO:1- MN	1.560	4.027	0.271	23.16	0.286	21.974	0.074	84.94
PM6:L8-BO:2- MN	1.545	4.066	0.271	23.22	0.285	22.063	0.071	87.95
PM6:L8- BO:2,7-MN	1.517	4.142	0.299	21.01	0.283	22.224	0.072	86.74

Table S9. The universality of 2-MN.

Active layer	V_{oc} (V)	FF (%)	J_{sc} (mA cm ⁻²)	PCE (%)
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PTB7-Th:PC ₇₁ BM	0.809	54.22	16.12	7.07
PTB7-Th:PC ₇₁ BM: 2-MN	0.807	68.09	17.91	9.84
PTB7-Th:IPY-T-IC	0.870	56.70	13.76	6.80
PTB7-Th:IPY-T-IC: 2-MN [38]	0.830	55.50	16.51	7.68
PM6:PTer-N25	0.960	38.32	11.62	4.25
PM6:PTer-N25: 2-MN [39]	0.940	65.13	19.52	11.94

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